

## 10A4

### 10.0AMPS SILICON RECTIFIERS

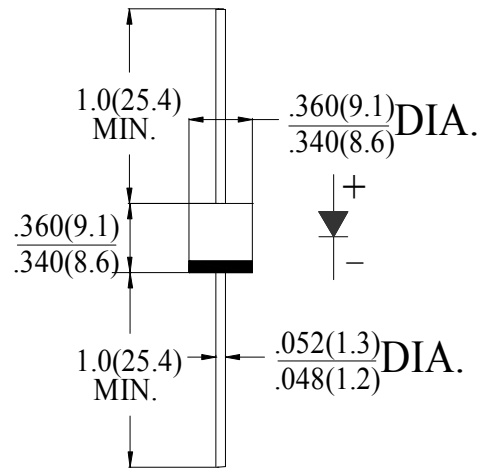
#### FEATURE

- . High current capability,
- . Low forward voltage drop
- . Low power loss, high efficiency
- . High surge capability
- . High temperature soldering guaranteed  
260°C /1 0sec/0.375" lead length at 5 lbs tension

#### MECHANICAL DATA

- . Terminal: Plated axial leads solderable per MIL-STD 202E, method 208C
- . Case: Molded with UL-94 Class V-0 recognized Flame Retardant Epoxy
- . Polarity: color band denotes cathode
- . Mounting position: any

#### R-6



Dimensions in inches and (millimeters)

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

Type Number	SYM BOL	10A4	units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	400	V
Maximum RMS Voltage	$V_{RMS}$	280	V
Maximum DC blocking Voltage	$V_{DC}$	400	V
Maximum Average Forward Rectified Current. 375" (9.5mm) lead length @ $T_A=75^\circ\text{C}$	$I_{F(AV)}$	10	A
Peak Forward Surge Current 8.3ms single half sine- wave superimposed on rated load (JEDEC method)	$I_{FSM}$	400	A
Maximum Forward Voltage at 10.0A DC	$V_F$	1.0	V
Maximum DC Reverse Current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	$I_R$	10.0 200.0	$\mu\text{A}$
Typical Junction Capacitance (Note1)	$C_J$	100	pF
Typical Thermal Resistance (Note2)	$R_{(JA)}$	10	$^\circ\text{C}/\text{W}$
Storage Temperature	$T_{STG}$	-55 to +150	$^\circ\text{C}$
Operation JunctionTemperature	$T_J$	-55 to +125	$^\circ\text{C}$

#### Note:

1. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
2. Thermal Resistance from Junction to Ambient

**RATING AND CHARACTERISTIC CURVES (10A4)**

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

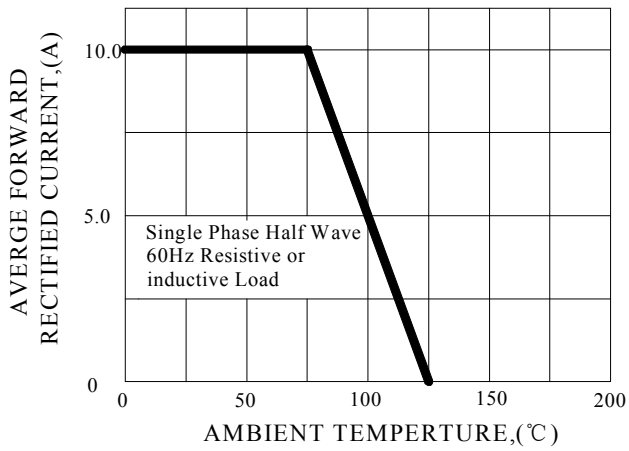


FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

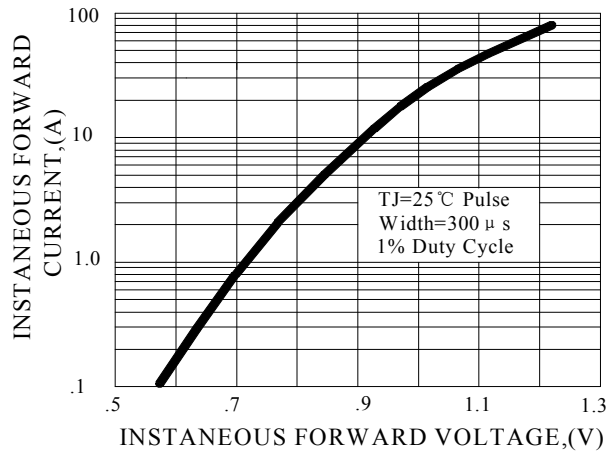


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

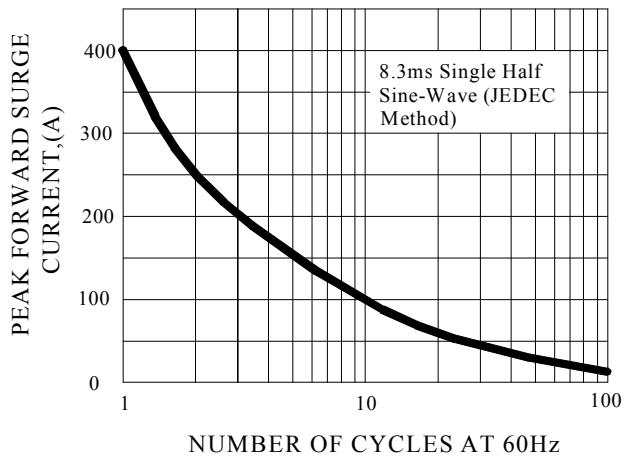


FIG.4-TYPICAL REVERSE CHARACTERISTICS

